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Form PTO-1449 (REV. 8-83) PATENT & TRADEMARK OFFICE INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary) DEC 0 5 2005				ATTY DOCKET NO. 118319 .				APPLICATION NO. 10/765,200		
			Ī	APPLICANT Mutsumi KIMURA						
				FILING DATE January 28, 2004			1 .	GROUP 2818		
TRADBASH		U.S. P	ATE	NT DOCU	MENTS					
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PO	1.	JP A 11-282995 w/Abstract and Translation	10/1	5/1999	Japan					
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	l	OTHER DOCUMENTS (Inc	ludin	g Author,	Title, Date, Per	tinent Pag	es, etc.)		<u> </u>	
PD	2.	S. Utsunomiya et al., "Low Temperatur Technology by Laser Ablation/Anneali	re Pol	y-SI TFT-	CD Transferr	ed onto Pl	astic Substrate I	Jsing Surface I	ree	
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Date: December 5, 2005